

FEATURES

AC PERFORMANCE

500 ns Settling to 0.01% for 10 V Step
75 V/ μ s Slew Rate
0.0001% Total Harmonic Distortion (THD)
13 MHz Gain Bandwidth
Internal Compensation for Gains of +2 or Greater

DC PERFORMANCE

0.5 mV max Offset Voltage (AD746B)
10 μ V/ $^{\circ}$ C max Drift (AD746B)
175 V/mV min Open Loop Gain (AD746B)
2 μ V p-p Noise, 0.1 Hz to 10 Hz
Available in Plastic Mini-DIP, Cerdip and Surface Mount Packages
Available in Tape and Reel in Accordance with EIA-481A Standard
MIL-STD-883B Processing also Available
Single Version: AD744

APPLICATIONS

Dual Output Buffers for 12- and 14-Bit DACs
Input Buffers for Precision ADCs, Wideband Preamplifiers and Low Distortion Audio Circuitry

PRODUCT DESCRIPTION

The AD746 is a dual operational amplifier, consisting of two AD744 BiFET op amps on a single chip. These precision monolithic op amps offer excellent dc characteristics plus rapid settling times, high slew rates and ample bandwidths. In addition, the AD746 provides the close matching ac and dc characteristics inherent to amplifiers sharing the same monolithic die.

The single pole response of the AD746 provides fast settling: 500 ns to 0.01%. This feature, combined with its high dc precision, makes it suitable for use as a buffer amplifier for 12- or 14-bit DACs and ADCs. Furthermore, the AD746's low total harmonic distortion (THD) level of 0.0001% and very close matching ac characteristics make it an ideal amplifier for many demanding audio applications.

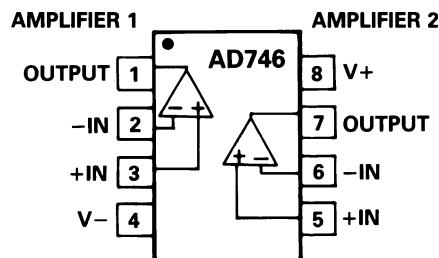
The AD746 is internally compensated for stable operation as a unity gain inverter or as a noninverting amplifier with a gain of 2 or greater. It is available in four performance grades. The AD746J is rated over the commercial temperature range of 0 to +70 $^{\circ}$ C. The AD746A and AD746B are rated over the industrial temperature range of -40 $^{\circ}$ C to +85 $^{\circ}$ C. The AD746S is rated over the military temperature range of -55 $^{\circ}$ C to +125 $^{\circ}$ C and is available processed to MIL-STD-883B, Rev. C.

REV. B

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CONNECTION DIAGRAM

Plastic Mini-DIP (N)
Cerdip (Q) and
Plastic SOIC (R) Packages



The AD746 is available in three 8-pin packages: plastic mini DIP, hermetic cerdip and surface mount (SOIC).

PRODUCT HIGHLIGHTS

1. The AD746 offers exceptional dynamic response for high speed data acquisition systems. It settles to 0.01% in 500 ns and has a 100% tested minimum slew rate of 50 V/ μ s (AD746B).
2. Outstanding dc precision is provided by a combination of Analog Devices' advanced processing technology, laser wafer drift trimming and well-matched ion-implanted JFETs. Input offset voltage, input bias current and input offset current are specified in the warmed-up condition and are 100% tested.
3. Differential and multichannel systems will benefit from the AD746's very close matching of ac characteristics. Input offset voltage specs are fully tested and guaranteed to a maximum of 0.5 mV (AD746B).
4. The AD746 has very close, guaranteed matching of input bias current between its two amplifiers.
5. Unity gain stable version AD712 also available.

AD746—SPECIFICATIONS (@ +25°C and ±15 V dc, unless otherwise noted)

Model	Conditions	Min	AD746J/A Typ	Max	Min	AD746B Typ	Max	Min	AD746S Typ	Max	Units	
INPUT OFFSET VOLTAGE ¹												
Initial Offset	T _{MIN} to T _{MAX}		0.3	1.5		0.25	0.5		0.3	1.0	mV	
Offset				2.0		0.7		1.5		mV		
vs. Temperature				20		10		20		μV/°C		
vs. Supply ² (PSRR)	T _{MIN} to T _{MAX}	80	95		84	100		80	95		dB	
vs. Supply (PSRR)		80			84			80			dB	
Long Term Stability				15		15		15			μV/month	
INPUT BIAS CURRENT ³												
Either Input	V _{CM} = 0 V		110	250		110	150		110	250	pA	
Either Input @ T _{MAX}	V _{CM} = 0 V		2.5/7	5.7/16		7	9.6		113	256	nA	
Either Input	V _{CM} = +10 V		145	350		145	200		145	350	pA	
Offset Current	V _{CM} = 0 V		45	125		45	75		45	125	pA	
Offset Current @ T _{MAX}	V _{CM} = 0 V		1.0/3	2.8/8		3	4.8		45	128	nA	
MATCHING CHARACTERISTICS												
Input Offset Voltage	T _{MIN} to T _{MAX}		0.6	1.5		0.3	0.5		0.6	1.0	mV	
Input Offset Voltage				2.0		0.7		1.5		mV		
Input Offset Voltage Drift				20		20		20		μV/°C		
Input Bias Current	@ 1 kHz			125			75			125	pA	
Crosstalk		@ 100 kHz	120		120		120		dB			
		@ 100 kHz	90		90		90		dB			
FREQUENCY RESPONSE												
Gain BW, Small Signal	G = -1	8	13		9	13		8	13		MHz	
Slew Rate, Unity Gain	G = -1	45	75		50	75		45	75		V/μs	
Full Power Response	V _O = 20 V p-p		600			600			600		kHz	
Settling Time to 0.01% ⁴	G = 1		0.5	0.75		0.5	0.75		0.5	0.75	μs	
Total Harmonic Distortion	f = 1 kHz R _I ≥ 2 kΩ V _O = 3 V rms		0.0001			0.0001			0.0001		%	
INPUT IMPEDANCE												
Differential			2.5 × 10 ¹¹ 5.5			2.5 × 10 ¹¹ 5.5			2.5 × 10 ¹¹ 5.5		Ω pF	
Common Mode			2.5 × 10 ¹¹ 5.5			2.5 × 10 ¹¹ 5.5			2.5 × 10 ¹¹ 5.5		Ω pF	
INPUT VOLTAGE RANGE												
Differential ⁵	V _{CM} = ±10 V T _{MIN} to T _{MAX} V _{CM} = ±11 V T _{MIN} to T _{MAX}		±20			±20			±20		V	
Common-Mode Voltage			+14.5, -11.5		+14.5, -11.5		+14.5, -11.5		+14.5, -11.5		V	
Over Max Operating Range ⁶		-11	+13	-11	+13	-11	+13	-11	+13	-11	+13	V
Common-Mode Rejection Ratio		78	88	82	88	78	88	78	88	78	88	dB
		76	84	80	84	76	84	76	84	76	84	dB
		72	84	78	84	72	84	72	84	72	84	dB
		70	80	74	80	70	80	70	80	70	80	dB
												dB
												dB
INPUT VOLTAGE NOISE												
0.1 to 10 Hz			2			2			2		μV p-p	
f = 10 Hz			45			45			45		nV/√Hz	
f = 100 Hz			22			22			22		nV/√Hz	
f = 1 kHz			18			18			18		nV/√Hz	
f = 10 kHz			16			16			16		nV/√Hz	
INPUT CURRENT NOISE												
f = 1 kHz			0.01			0.01			0.01		pA/√Hz	
OPEN LOOP GAIN												
V _O = ±10 V	R _I ≥ 2 kΩ T _{MIN} to T _{MAX}											
R _I ≥ 2 kΩ		150	300	175	300	150	300	150	300		V/mV	
T _{MIN} to T _{MAX}		75	200	75	200	65	175			V/mV		
OUTPUT CHARACTERISTICS												
Voltage	R _I ≥ 2 kΩ	+13, -12.5	+13.9, -13.3		+13, -12.5	+13.9, -13.3		+13, -12.5	+13.9, -13.3		V	
	T _{MIN} to T _{MAX}	±12	+13.8, -13.1		±12	+13.8, -13.1		±12	+13.8, -13.1		V	
Current	Short Circuit		25			25			25		mA	
Max Capacitive Load	Gain = -1		50			50			50		pF	
Driving Capability	Gain = -10		500			500			500		pF	
POWER SUPPLY												
Rated Performance			±15			±15			±15		V	
Operating Range		±4.5		±18	±4.5		±18	±4.5		±18	V	
Quiescent Current		7	10	7	8.0	7	10			mA		
TEMPERATURE RANGE												
Rated Performance		0 to +70/-40 to +85		-40 to +85		-55 to +125					°C	
PACKAGE OPTIONS												
8-Pin Plastic Mini-DIP (N-8)		AD746JN		AD746BQ		AD746SQ						
8-Pin Cerdip (Q-8)		AD746AQ										
8-Pin Surface Mount (R-8)		AD746JR										
Tape and Reel		AD746JR-REEL										
Chips								AD746SCHIPS				
TRANSISTOR COUNT												
		54		54		54						

NOTES

¹Input Offset Voltage specifications are guaranteed after 5 minutes of operation at $T_A = +25^\circ\text{C}$.

²PSRR test conditions: $+V_S = 15\text{ V}$, $-V_S = -12\text{ V}$ to -18 V and $+V_S = 12\text{ V}$ to 18 V , $-V_S = -15\text{ V}$.

³Bias Current Specifications are guaranteed maximum at either input after 5 minutes of operation at $T_A = +25^\circ\text{C}$. For higher temperature, the current doubles every 10°C .

⁴Gain = -1 , $R_I = 2\text{ k}\Omega$, $C_I = 10\text{ pF}$.

⁵Defined as voltage between inputs, such that neither exceeds $\pm 10\text{ V}$ from ground.

⁶Typically exceeding -14.1 V negative common-mode voltage on either input results in an output phase reversal.

Specifications subject to change without notice.

Specifications in **boldface** are tested on all production units at final electrical test. Results from those tests are used to calculate outgoing quality levels. All min and max specifications are guaranteed, although only those shown in **boldface** are tested on all production units.

ABSOLUTE MAXIMUM RATINGS¹

Supply Voltage $\pm 18\text{ V}$

Internal Power Dissipation² 500 mW

Input Voltage $\pm V_S$

Output Short Circuit Duration
(For One Amplifier) Indefinite

Differential Input Voltage $+V_S$ and $-V_S$

Storage Temperature Range (Q) -65°C to $+150^\circ\text{C}$

Storage Temperature Range (N, R) -65°C to $+125^\circ\text{C}$

Operating Temperature Range

AD746J 0°C to $+70^\circ\text{C}$

AD746A/B -40°C to $+85^\circ\text{C}$

AD746S -55°C to $+125^\circ\text{C}$

Lead Temperature Range

(Soldering 60 seconds) $+300^\circ\text{C}$

ESD Rating

NOTES

¹Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

²8-Pin Plastic Package: $\theta_{JA} = 100^\circ\text{C/Watt}$, $\theta_{JC} = 50^\circ\text{C/Watt}$

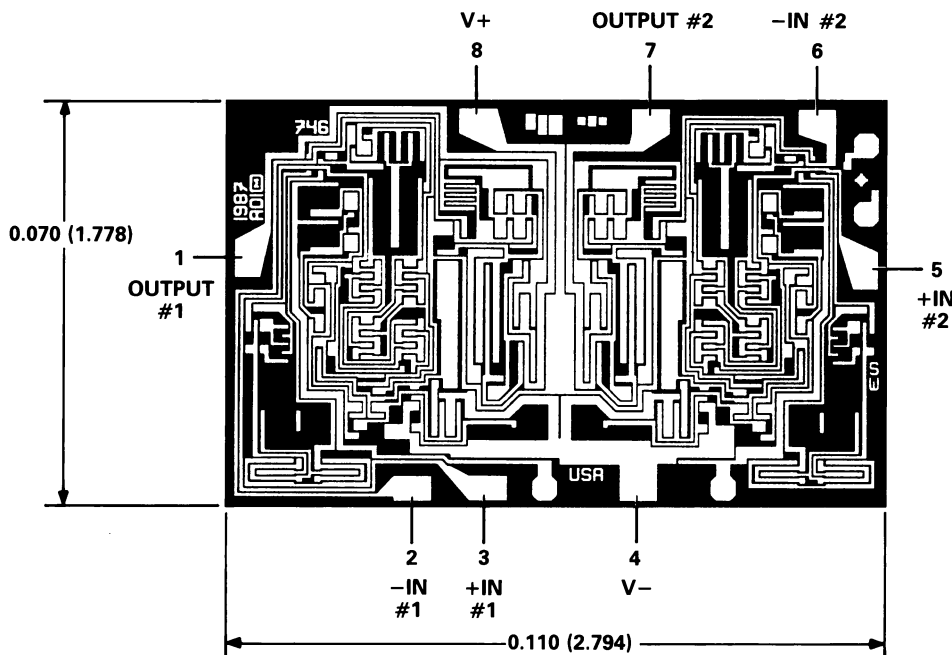
8-Pin Cerdip Package: $\theta_{JA} = 110^\circ\text{C/Watt}$, $\theta_{JC} = 30^\circ\text{C/Watt}$

8-Pin Small Outline Package: $\theta_{JA} = 160^\circ\text{C/Watt}$, $\theta_{JC} = 42^\circ\text{C/Watt}$

METALIZATION PHOTOGRAPH

Contact factory for latest dimensions.

Dimensions shown in inches and (mm).

**CAUTION**

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the AD746 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



AD746—Typical Characteristics

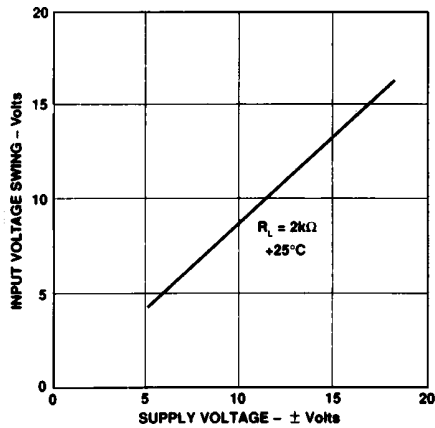


Figure 1. Input Voltage Swing vs. Supply Voltage

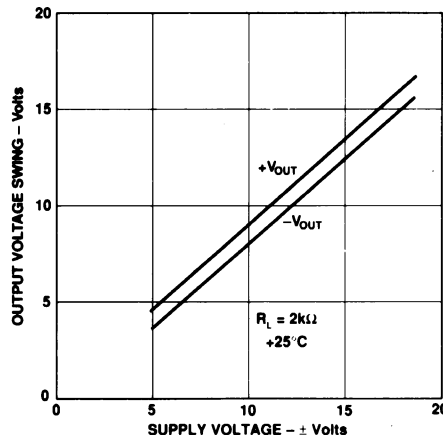


Figure 2. Output Voltage Swing vs. Supply Voltage

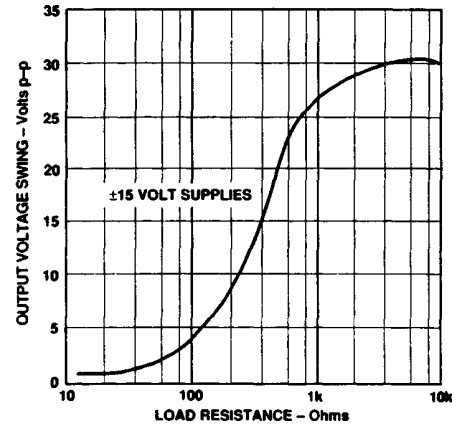


Figure 3. Output Voltage Swing vs. Load Resistance

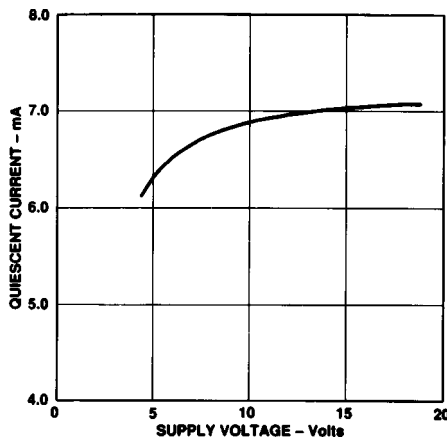


Figure 4. Quiescent Current vs. Supply Voltage

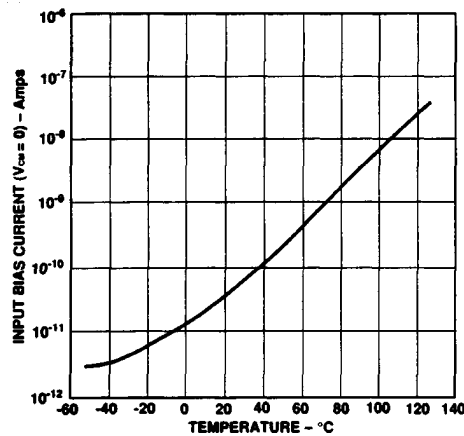


Figure 5. Input Bias Current vs. Temperature

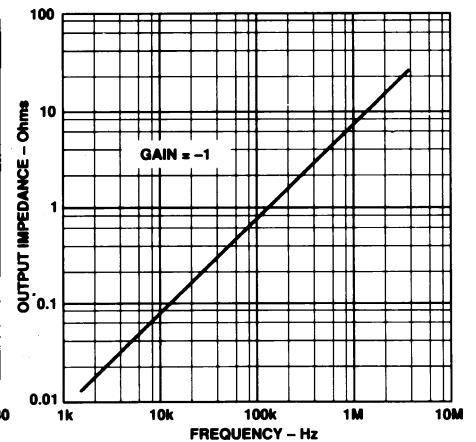


Figure 6. Output Impedance vs. Frequency

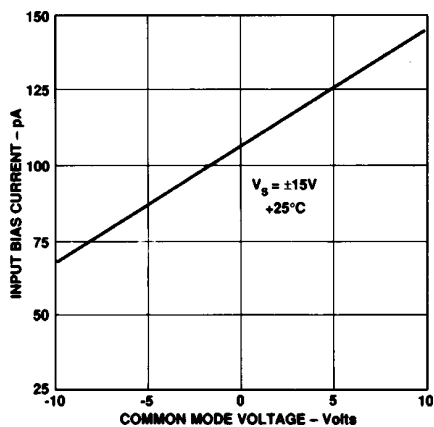


Figure 7. Input Bias Current vs. Common Mode Voltage

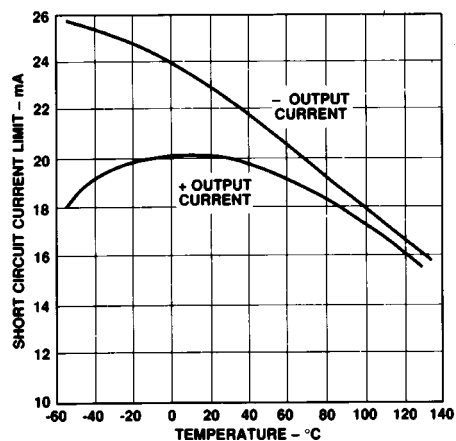


Figure 8. Short Circuit Current Limit vs. Temperature

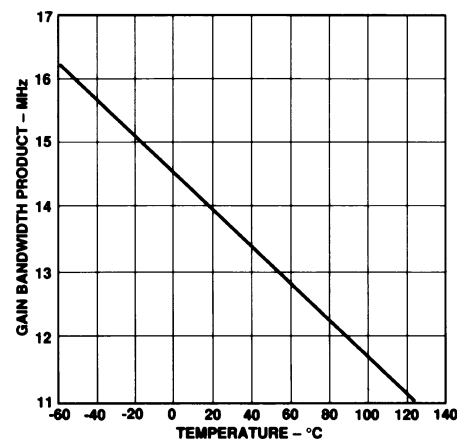


Figure 9. Gain Bandwidth Product vs. Temperature

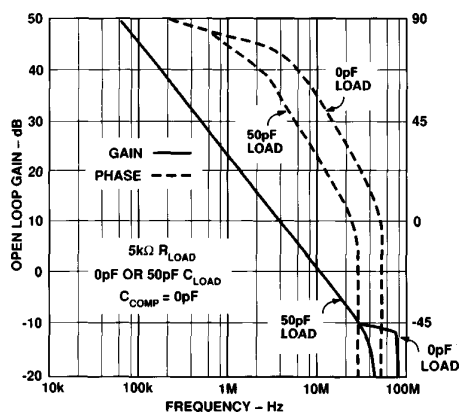


Figure 10. Open Loop Gain and Phase Margin vs. Frequency

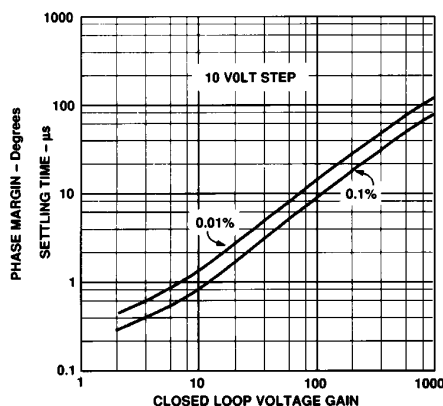


Figure 11. Settling Time vs. Closed Loop Voltage Gain

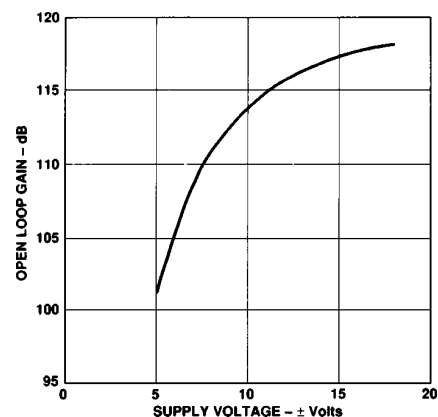


Figure 12. Open Loop Gain vs. Supply Voltage

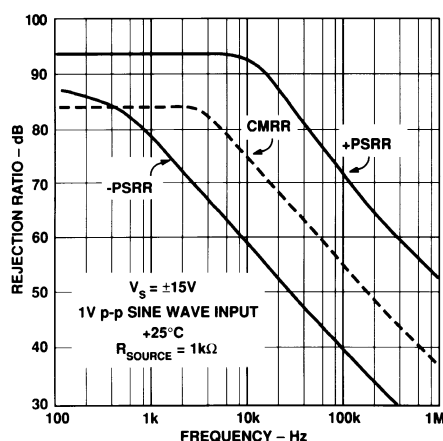


Figure 13. Common-Mode and Power Supply Rejection vs. Frequency

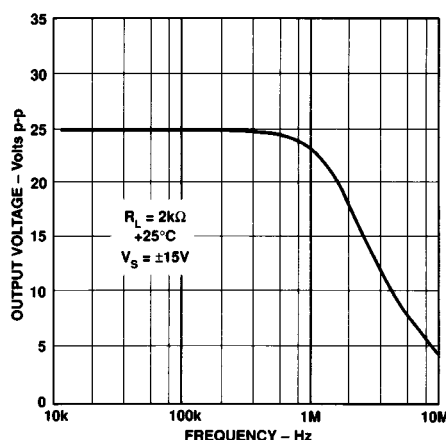


Figure 14. Large Signal Frequency Response

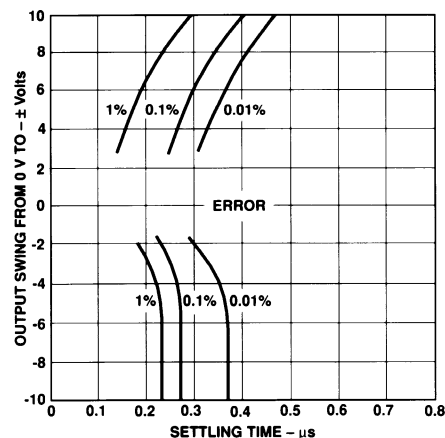


Figure 15. Output Swing and Error vs. Settling Time

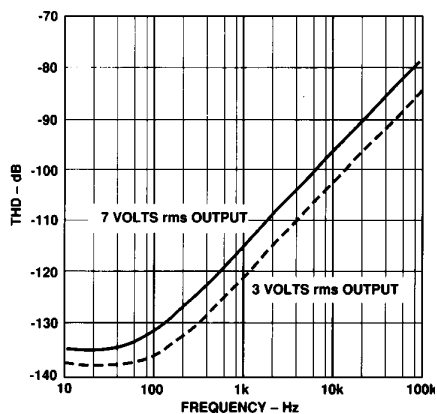


Figure 16. Total Harmonic Distortion vs. Frequency Using Circuit of Figure 19

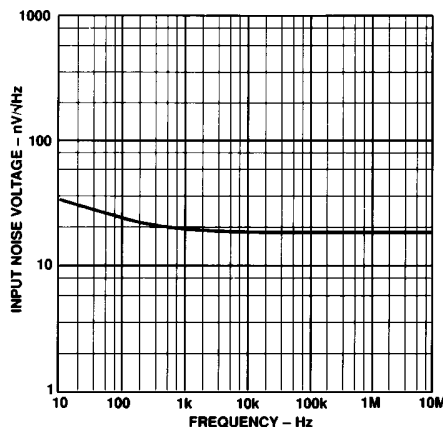


Figure 17. Input Noise Voltage Spectral Density

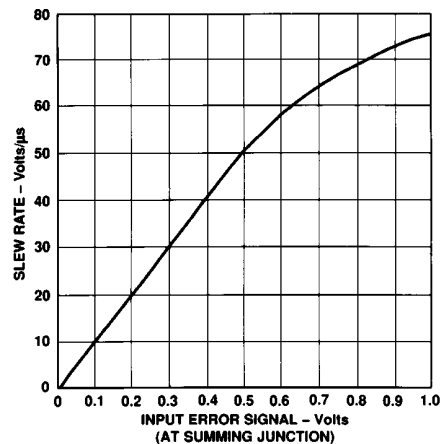


Figure 18. Slew Rate vs. Input Error Signal

AD746

POWER SUPPLY BYPASSING

The power supply connections to the AD746 must maintain a low impedance to ground over a bandwidth of 13 MHz or more. This is especially important when driving a significant resistive or capacitive load, since all current delivered to the load comes from the power supplies. Multiple high quality bypass capacitors are recommended for each power supply line in any critical application. A 0.1 μF ceramic and a 1 μF tantalum capacitor as shown in Figure 20 placed as close as possible to the amplifier

(with short lead lengths to power supply common) will assure adequate high frequency bypassing, in most applications. A minimum bypass capacitance of 0.1 μF should be used for any application.

If only one of the two amplifiers inside the AD746 is to be utilized, the unused amplifier should be connected as shown in Figure 21a. Note that the noninverting input should be grounded and that R_L and C_L are not required.

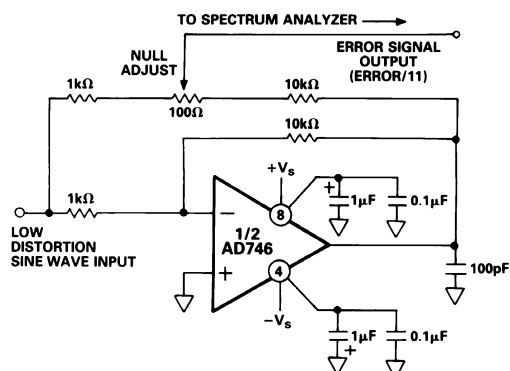


Figure 19. THD Test Circuit

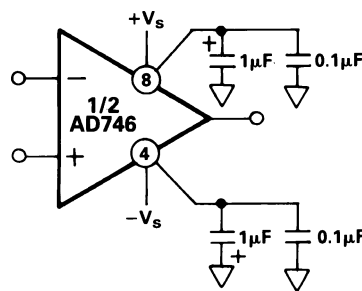


Figure 20. Power Supply Bypassing

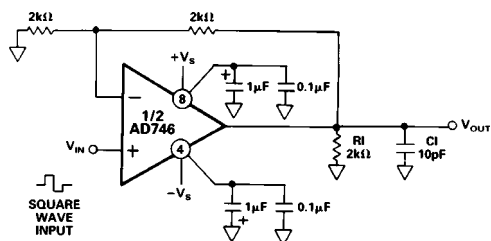


Figure 21a. Gain of 2 Follower

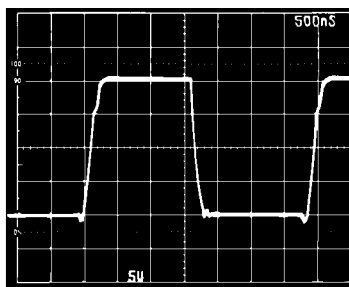


Figure 21b. Gain of 2 Follower Large Signal Pulse Response

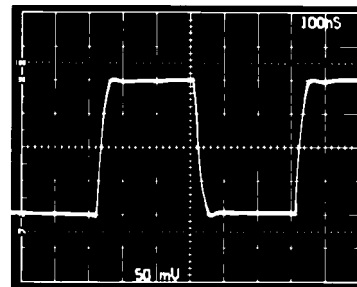


Figure 21c. Gain of 2 Follower Small Signal Pulse Response

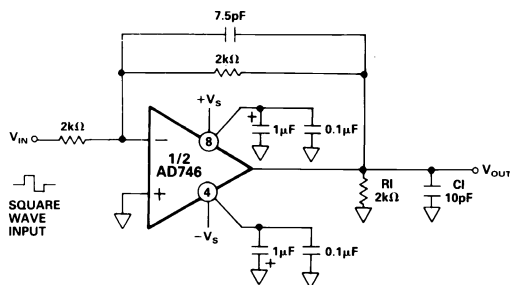


Figure 22a. Unity Gain Inverter

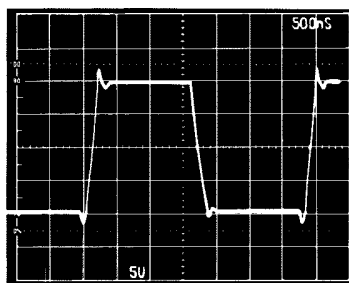


Figure 22b. Unity Gain Inverter Large Signal Pulse Response

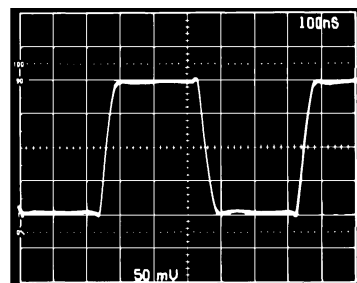
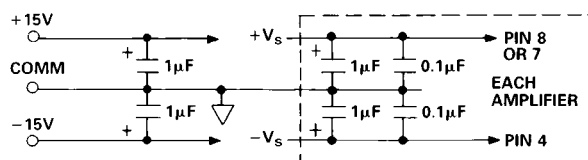
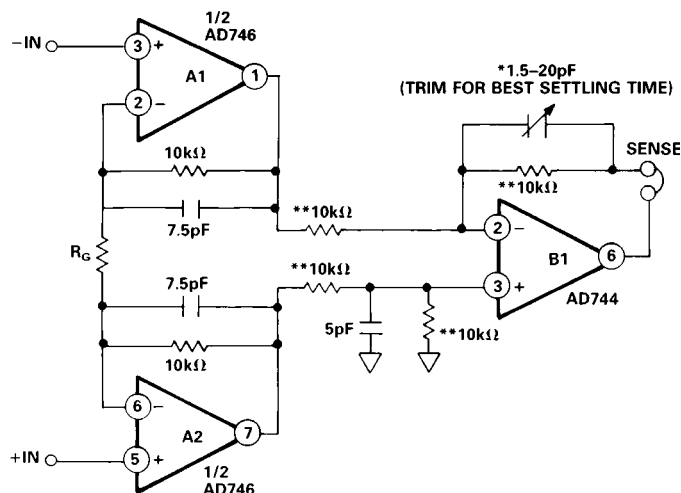


Figure 22c. Unity Gain Inverter Small Signal Pulse Response

A HIGH SPEED 3 OP AMP INSTRUMENTATION AMPLIFIER CIRCUIT

The instrumentation amplifier circuit shown in Figure 23 can provide a range of gains from 2 up to 1000 and higher. The circuit bandwidth is 2.5 MHz at a gain of 2 and 750 kHz at a gain of 10; settling time for the entire circuit is less than 2 μ s to within 0.01% for a 10 volt step, ($G = 10$).

$$\text{CIRCUIT GAIN} = \frac{20,000}{R_G} + 1$$



*VOLTRONICS SP20 TRIMMER CAPACITOR OR EQUIVALENT
**RATIO MATCHED 1% METAL FILM RESISTORS

Figure 23. A High Performance, 3 Op Amp, Instrumentation Amplifier Circuit

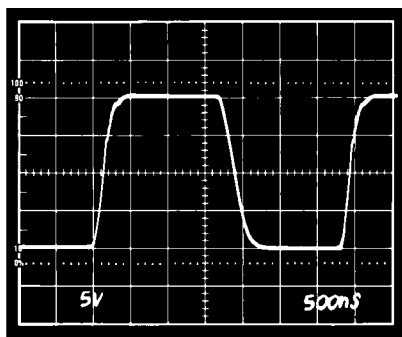


Figure 24. Pulse Response of the 3 Op Amp Instrumentation Amplifier. Gain = 10, Horizontal Scale: 0.5 μ s/Div, Vertical Scale: 5 V/Div.

Table I. Performance Summary for the 3 Op Amp Instrumentation Amplifier Circuit

Gain	R_G	Bandwidth	T_{SETTLE} (0.01%)
2	20 k Ω	2.5 MHz	1.0 μ s
10	4.04 k Ω	1 MHz	2.0 μ s
100	404 Ω	290 kHz	5.0 μ s

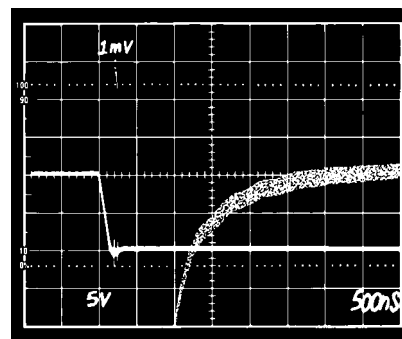


Figure 25. Settling Time of the 3 Op Amp Instrumentation Amplifier. Gain = 10, Horizontal Scale: 0.5 μ s/Div, Vertical Scale: 5 V/Div. Error Signal Scale: 0.01%/Div.

THD Performance Considerations

The AD746 was carefully optimized to offer excellent performance in terms of total harmonic distortion (THD) in signal processing applications. The THD level when operating the AD746 in inverting gain applications will show a gradual rise from the distortion floor of 20 dB/decade (see Figure 28). In noninverting applications, care should be taken to balance the source impedances at both the inverting and noninverting inputs, to avoid distortion caused by the modulation of input capacitance inherent in all BiFET op amps.

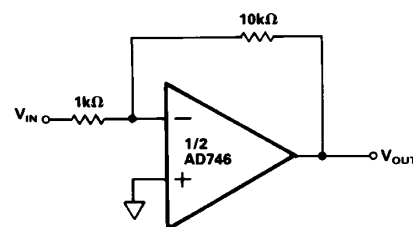


Figure 26. THD Measurement, Inverter Circuit

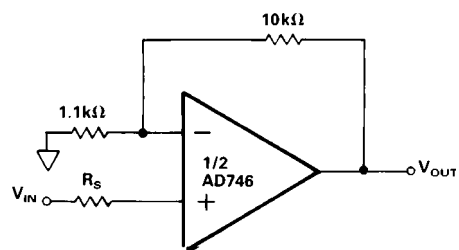


Figure 27. THD Measurement, Follower Circuit

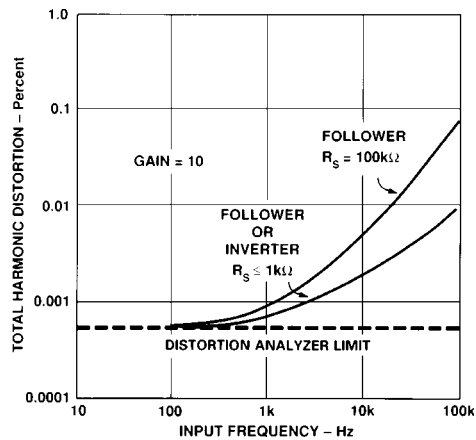


Figure 28. THD vs. Frequency Using Standard Distortion Analyzer

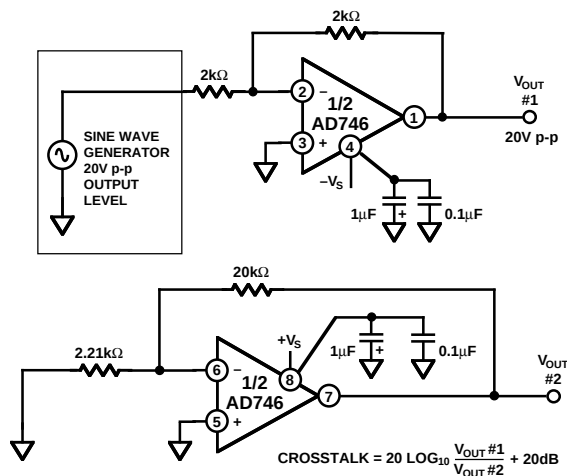


Figure 29. Crosstalk Test Circuit

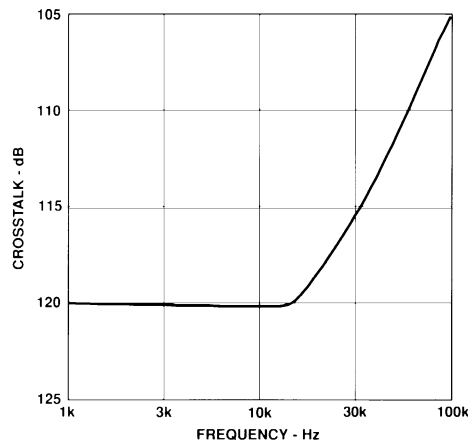
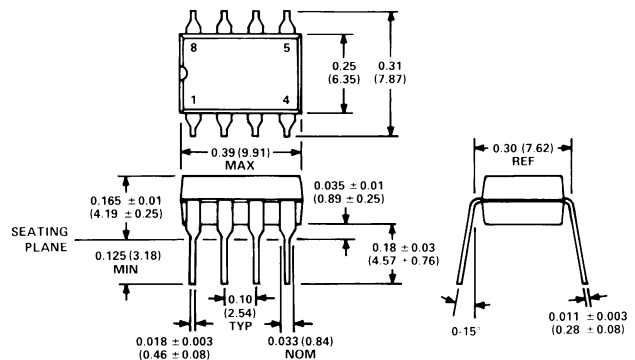


Figure 30. Crosstalk vs. Frequency

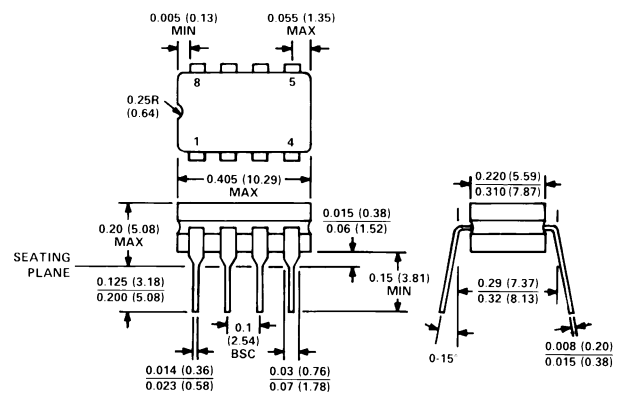
OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

Mini-DIP (N) Package



Cerdip (Q) Package



Plastic Small Outline (R) Package

